

Features:

- Isolated mounting base 3000V~
- Pressure contact technology with Increased power cycling capability
- Space and weight savings

Typical Applications

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

$I_{T(AV)}$ **40A**
 V_{DRM}/V_{RRM} **1900~2500V**
 I_{TSM} **$1.15A \times 10^3$**
 I^2t **$6.60A^2 \cdot S \cdot 10^3$**



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _J (°C)	VALUE			UNIT
				Min	Type	Max	
I _{T(AV)}	Mean on-state current	180° half sine wave 50Hz Single side cooled, T _c =85°C	125			40	A
I _{T(RMS)}	RMS on-state current		125			63	A
V _{DRM} V _{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	V _{DRM} &V _{RRM} tp=10ms V _{DSM} &V _{RSM} = V _{DRM} &V _{RRM} +100V respectively	125	1900		2500	V
I _{DRM} I _{RRM}	Repetitive peak current	at V _{DRM} at V _{RRM}	125			10	mA
I _{TSM}	Surge on-state current	10ms half sine wave	125			1.15	KA
I ² t	I ² T for fusing coordination	V _R =60%V _{RRM}					6.60
V _{TO}	Threshold voltage		125			0.85	V
r _T	On-state slop resistance						5.57
V _{TM}	Peak on-state voltage	I _{TM} =120A	25			1.85	V
dv/dt	Critical rate of rise of off-state voltage	V _{DM} =67%V _{DRM}	125			800	V/μs
di/dt	Critical rate of rise of on-state current	I _{TM} =110A, Gate source 1.5A t _r ≤0.5μs Repetitive	125			50	A/μs
I _{GT}	Gate trigger current	V _A =12V, I _A =1A	25	30		100	mA
V _{GT}	Gate trigger voltage			0.8		2.5	V
I _H	Holding current			20		150	mA
V _{GD}	Non-trigger gate voltage	V _{DM} =67%V _{DRM}	125	0.2			V
R _{th(j-c)}	Thermal resistance Junction to case	Single side cooled				0.65	°C/W
R _{th(c-h)}	Thermal resistance case to heat sink	Single side cooled				0.2	°C/W
V _{iso}	Isolation voltage	50Hz, R.M.S, t=1min, liso:1mA(MAX)		3000			V
F _m	Thermal connection torque (M5)				4.0		N·m
	Mounting torque (M6)				6.0		N·m
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				115		g
Outline	215F3/223F3						

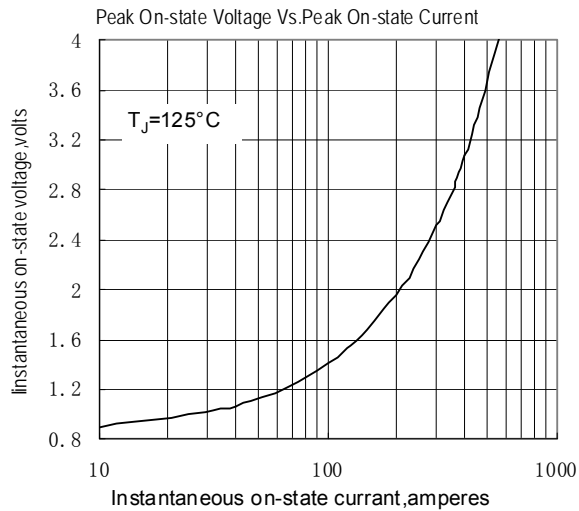


Fig. 1

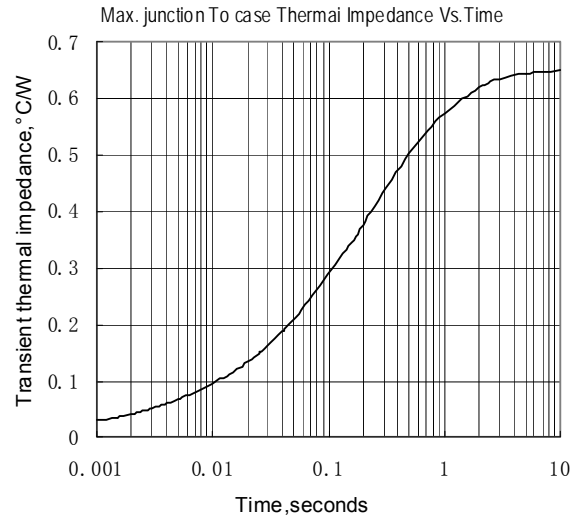


Fig. 2

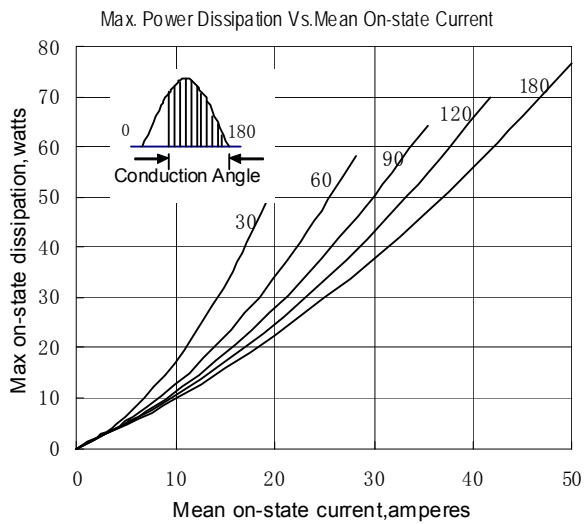


Fig. 3

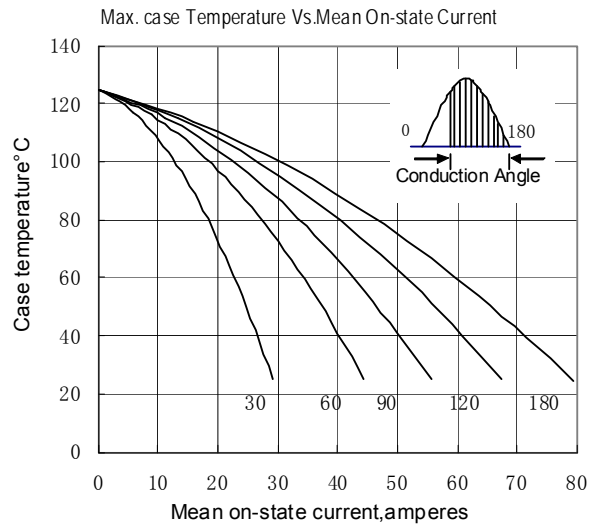


Fig. 4

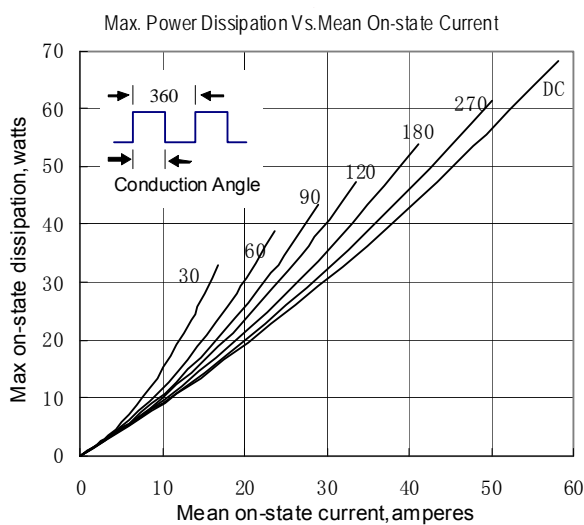


Fig. 5

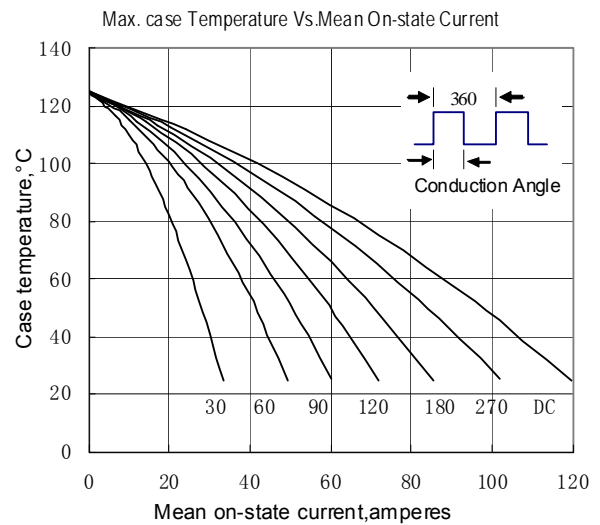


Fig. 6

Surge Current Vs.Cycles

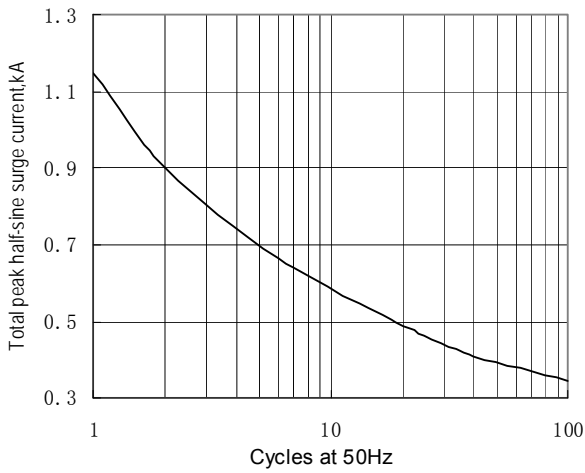


Fig.7

I_t^2 Vs.Time

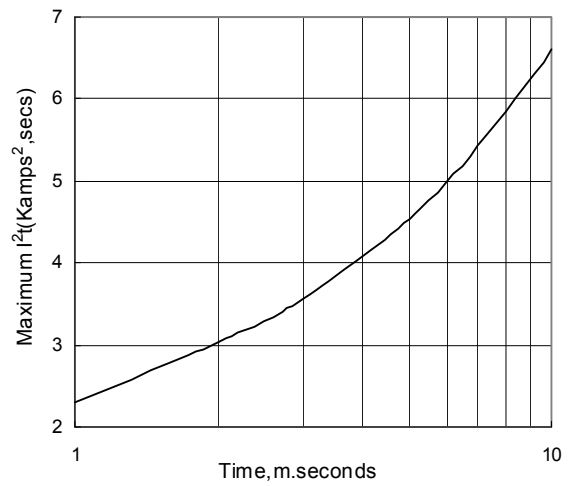


Fig.8

Gate characteristic at 25°C junction temperature

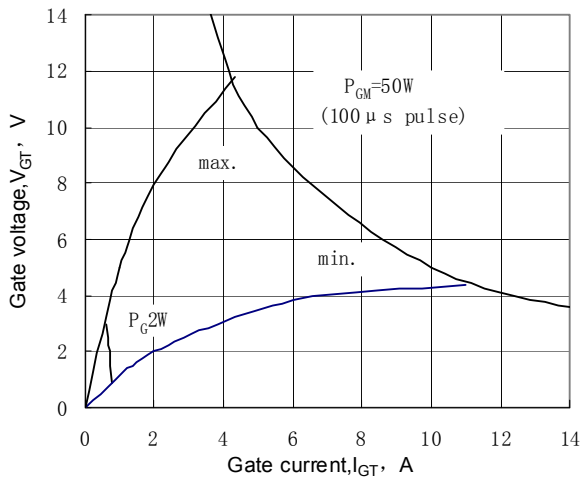


Fig.9

Gate Trigger Zone at varies temperature

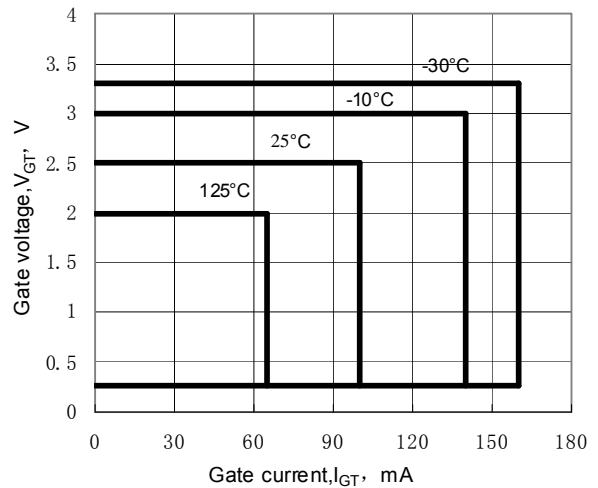


Fig.10

Outline:

